## PATENT COOPERATION TREATY

## PCT

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# INTERNATIONAL PRELIMINARY REPORT ON PATENTABILITY

(Chapter II of the Patent Cooperation Treaty)

(PCT Article 36 and Rule 70)

Applicant's or agent's file reference TJ0402-PCT		FOR FURTHER	ACTION	See Form PCT/IPEA/416				
International application No. PCT/JP2004/008516		International filing da 10.06.2004	·	Priority date (day/month/year) 11.07.2003				
Interna	ational Patent Cla	ssification (IPC) or n	ational classification and IPC		11.07.2005			
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Applic								
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1.	This report is th	e international pre	liminary examination	report established by	y this International Preliminary Examining			
	Authority under	Article 35 and tran	nsmitted to the applica	report, established by ant according to Artic	y this international Preliminary Examining			
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4	a. 🛭 sent to ti	the applicant and to the International Bureau) a total of 3 sheets, as follows:						
	and/	or sheets containir	e description, claims and/or drawings which have been amended and are the basis of this report to containing rectifications authorized by this Authority (see Rule 70.16 and Section 607 of the					
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	beyond the disclosure in the international application as filed, as indicated in item 4 of Box No. I and the							
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## INTERNATIONAL PRELIMINARY REPORT ON PATENTABILITY

International application No. PCT/JP2004/008516

	Box No. I Basis of the repo	rt				
1.	With regard to the language, t filed, unless otherwise indicate	his report is based on the international application in the language in which it was				
	which is the language of a  international search (un  publication of the intern	This report is based on translations from the original language into the following language, which is the language of a translation furnished for the purposes of:  international search (under Rules 12.3 and 23.1(b))  publication of the international application (under Rule 12.4)  international preliminary examination (under Rules 55.2 and/or 55.3)				
2.	nave been turnished to the red	regard to the <b>elements*</b> of the international application, this report is based on <i>(replacement sheets which been furnished to the receiving Office in response to an invitation under Article 14 are referred to in this t as "originally filed" and are not annexed to this report):</i>				
	Description, Pages					
	1-22	as originally filed				
	Claims, Numbers					
	2	as originally filed				
	1, 3-6	received on 02.05.2005 with letter of 28.04.2005				
	Drawings, Sheets	•				
	1/11-11/11	as originally filed				
	☐ a sequence listing and/or	any related table(s) - see Supplemental Box Relating to Sequence Listing				
3.	<ul> <li>☐ The amendments have resulted in the cancellation of:</li> <li>☐ the description, pages</li> <li>☐ the claims, Nos.</li> <li>☐ the drawings, sheets/figs</li> <li>☐ the sequence listing (specify):</li> <li>☐ any table(s) related to sequence listing (specify):</li> </ul>					
4	had not been made, since the Supplemental Box (Rule 70.2  ☐ the description, pages ☐ the claims, Nos. 1,5 ☐ the drawings, sheets for the sequence listing (any table(s) related to	igs specify): sequence listing <i>(specify)</i> :				
	* If item 4 applies,	some or all of these sheets may be marked "superseded."				

## INTERNATIONAL PRELIMINARY REPORT ON PATENTABILITY

International application No. PCT/JP2004/008516

Box No. V Reasoned statement under Article 35(2) with regard to novelty, inventive step or industrial applicability; citations and explanations supporting such statement

1. Statement

Novelty (N)

Yes: Claims

1-6

No: Claims

Inventive step (IS)

Yes: Claims

1-6

No: Claims

Industrial applicability (IA)

Yes: Claims

1-6

No: Claims

2. Citations and explanations (Rule 70.7):

see separate sheet

Box No. VIII Certain observations on the international application

The following observations on the clarity of the claims, description, and drawings or on the question whether the claims are fully supported by the description, are made:

see separate sheet

### Re Item I Basis of the report

The amendments filed with the letter dated 28.04.2005 introduce subject-matter which extends beyond the content of the application as filed, contrary to Article 34(2)(b) PCT. The amendments concerned are the following.

Amendment in claims 1 and 5: "a drift region of n-type semiconductor provided below the active device", although it is written in page 2, lines 1-2: "beneath the p body region, n drift region is provided". Because the active device might not be the body region, this amendment goes beyond the application as filed.

### Re Item V

Reasoned statement with regard to novelty, inventive step or industrial applicability; citations and explanations supporting such statement

- Reference is made to the following documents: 1.
  - D1: US-B1-6 452 228 (HARA KUNIHIKO ET AL) 17 September 2002 (2002-09-17)
  - D2: US-B1-6 271 562 (GRAF HEIMO ET AL) 7 August 2001 (2001-08-07)
- The closest prior art for claims 1-4 is seen as document D1 which discloses a vertical 2. power MOSFET which differs from the invention in that in the invention:
  - a part of the boundary of the source electrode with the insulation layer is in contact with a p-type region;
  - a p-type region contacts the drain electrode.

The subject-matter of claims 1-4 is therefore new in the sense of Article 33(2) PCT.

The closest prior art for claims 5 and 6 is seen as document D2 which describes an insulated gate bipolar transistor which differs from the invention in that in the invention a part of the boundary of the source electrode with the insulation layer is in contact with a p-type region.

The subject-matter of claims 5 and 6 is therefore new in the sense of Article 33(2) PCT.

As there is no indication in any of the prior art references of an insulated gate bipolar transistor whose boundary of the source electrode with the insulation layer has a part in contact with a p-type region, the subject-matter of claims 1-6 is inventive in the sense of Article 33(3) PCT.

### Re Item VIII

## Certain observations on the international application

- The application does not meet the requirements of Article 6 PCT, because claims 1 and 5 are not clear.
- 1.1 It is written in claim 1: "a collector region of p-type semiconductor provided contacting and below the drift region". However, it is not clear what the collector is contacting.
- 1.2 It is written in claims 1 and 5: "an end portion of conducting portion of the active device to the contact electrode". Nevertheless, it is not clear what "an end portion [...] to the contact electrode" is.
- 1.3 The expression "marginal corner" is not clear in claim 1. Indeed, the difference between a "normal" corner and a "marginal" corner is not clear.
- Claims 1 and 5 are not supported by the description as required by Article 6 PCT, as their scope is broader than justified by the description and drawings. Indeed, no gate electrode is claimed, although it is clear from the description that two gate electrodes are provided (see figure 20 and page 2, line 10).
- 3. The feature "collector region" in claims 1 and 5 is not clear because if the feature is intended to specify that the device is a bipolar transistor, then a bipolar transistor

should be claimed.

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#### CLAIMS

1. (Amended) A semiconductor device comprising:

an active device provided in a semiconductor substrate facing its principal plane,

a contact electrode provided outside of the semiconductor substrate conducting with the active device,

a drift region of N-type semiconductor provided below the active device, and

a collector region of P-type semiconductor provided contacting and below the drift region,

wherein an end portion of conducting portion of the active device to the contact electrode is composed with P-type semiconductor, and a marginal corner of the end portion on the P-type region of the active device is formed with a curved line or with an obtuse angle.

2. (Unchanged) A semiconductor device of claim 1,

wherein a plurality of active devices are discretely arranged in the semiconductor substrate, and each active device has a conducting portion to a contact electrode, and

a corner portion of a conducting portion of an active device positioned at the end and at opposite side to another active device is formed with a curved line or with an obtuse angle.

3. (Amended) A semiconductor device of claim 1,

wherein the shape of conducting portion of the active device to the contact electrode is formed in a broader width in an end portion than in the central portion.

4. (Amended) A semiconductor device of claim 3,

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wherein a plurality of active devices are discretely arranged in the semiconductor substrate, and each active device has a conducting portion to a contact electrode,

an end portion of a conducting portion of an active device positioned at an end and at opposite side of another active device is formed broader than the central portion of the conducting portion, and

a corner portion of the end portion is formed with a curved line or with an obtuse angle.

5. (Amended) A semiconductor device comprising:

an active device provided in a semiconductor substrate facing its principal plane,

a contact electrode provided outside of the semiconductor substrate conducting with the active device,

a drift region of N-type semiconductor provided below the active device, and

a collector region of P-type semiconductor provided contacting and below the drift region,

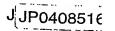
wherein an end portion of conducting portion of the active device to the contact electrode is composed with P-type semiconductor, and impurity concentration within the conducting portion is lower at a corner portion of conducting portion than in other portion of it.

6. (Amended) A semiconductor device of claim 5,

wherein a plurality of active devices are discretely arranged in the semiconductor substrate, and each active device has a conducting portion to a contact electrode, and

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a corner portion of a conducting portion of an active device positioned at an end and at opposite side of another active device is lower in impurity concentration than other portion of the conducting portion.